# **BLF571**

# HF / VHF power LDMOS transistor

Rev. 01 — 11 December 2008

**Preliminary data sheet** 

# 1. Product profile

#### 1.1 General description

A 20 W LDMOS RF transistor for broadcast applications and industrial applications in the HF and VHF band.

Table 1. Production test performance

Mode of operation	f	V <sub>DS</sub>	P <sub>L</sub>	Gp	$\eta_{D}$
	(MHz)	(V)	(W)	(dB)	(%)
CW	225	50	20	27.5	70

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

#### 1.2 Features

- Typical CW performance at frequency of 225 MHz, a supply voltage of 50 V and an I<sub>Dq</sub> of 50 mA:
  - ◆ Average output power = 20 W
  - ◆ Power gain = 27.5 dB
  - ◆ Efficiency = 70 %
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (10 MHz to 500 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications



#### **HF / VHF power LDMOS transistor**

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		
2	gate		1 
3	source	2 3	2 — 3 3 sym112

<sup>[1]</sup> Connected to flange.

# 3. Ordering information

Table 3. Ordering information

Type number	Package	e	
	Name	Description	Version
BLF571	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT467C

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	110	V
$V_{GS}$	gate-source voltage		-0.5	+11	V
$I_D$	drain current		-	3.6	Α
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	225	°C

#### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case}$ = 80 °C; $P_L$ = 20 W	2.9	K/W

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# 6. Characteristics

Table 6. DC characteristics

 $T_i = 25 \,^{\circ}C$  unless otherwise specified

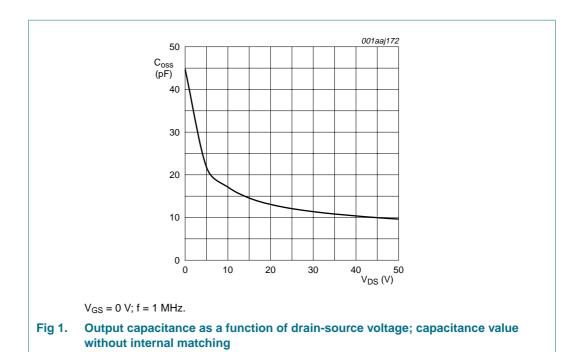
,	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.25 \text{ mA}$	110	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_{D} = 25 \text{ mA}$	1.25	1.7	2.25	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 50 \text{ V}; I_{D} = 50 \text{ mA}$	1.25	1.75	2.25	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \ V; \ V_{DS} = 50 \ V$	-	-	1.4	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	3.0	3.6	-	Α
$I_{GSS}$	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	140	nΑ
9 <sub>fs</sub>	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 1.25 \text{ A}$	-	1.8	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 833 \text{ mA}$	-	1.34	-	Ω
C <sub>rs</sub>	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	0.18	-	pF
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	22.9	-	pF
C <sub>oss</sub>	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V};$ f = 1 MHz	-	9.64	-	pF

Table 7. RF characteristics

Mode of operation: CW; f = 225 MHz; RF performance at  $V_{DS}$  = 50 V;  $I_{Dq}$  = 50 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$G_p$	power gain	$P_{L} = 20 \text{ W}$	25.5	27.5	29.5	dB
$RL_{in}$	input return loss	$P_{L} = 20 \text{ W}$	10	13	-	dB
$\eta_{D}$	drain efficiency	$P_{L} = 20 \text{ W}$	67	70	-	%

#### **HF / VHF power LDMOS transistor**



# 6.1 Ruggedness in class-AB operation

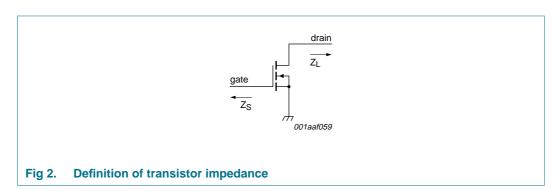
The BLF571 is capable of withstanding a load mismatch corresponding to VSWR = 13 : 1 through all phases under the following conditions:  $V_{DS}$  = 50 V;  $I_{Dq}$  = 50 mA;  $P_{L}$  = 20 W; f = 225 MHz.

# 7. Application information

### 7.1 Impedance information

**Table 8. Typical impedance** Simulated  $Z_S$  and  $Z_L$  test circuit impedances.

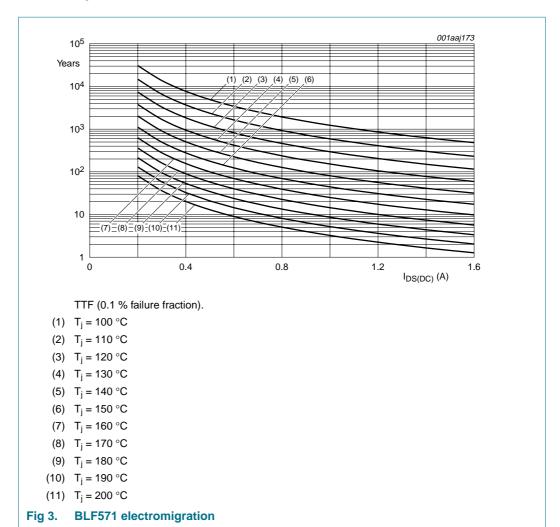
f	Z <sub>S</sub>	Z <sub>L</sub>
MHz	Ω	Ω
225	9.7 + j31.5	31.7 + j29.3



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# 7.2 Reliability

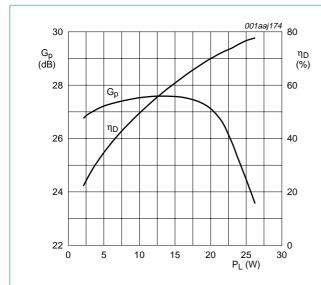


# 8. Test information

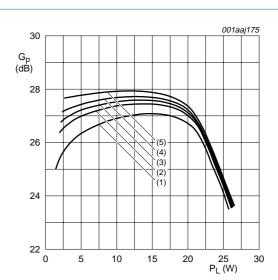
### 8.1 RF performance

The following figures are measured in a class-AB production test circuit.

#### 8.1.1 1-Tone CW



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 50 mA; f = 225 MHz.



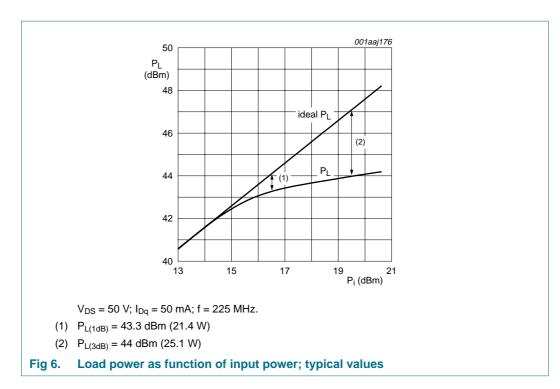
 $V_{DS} = 50 \text{ V}$ ; f = 225 MHz.

- (1)  $I_{Dq} = 20 \text{ mA}$
- (2)  $I_{Dq} = 40 \text{ mA}$
- (3)  $I_{Dq} = 50 \text{ mA}$
- (4)  $I_{Dq} = 60 \text{ mA}$
- (5)  $I_{Dq} = 80 \text{ mA}$

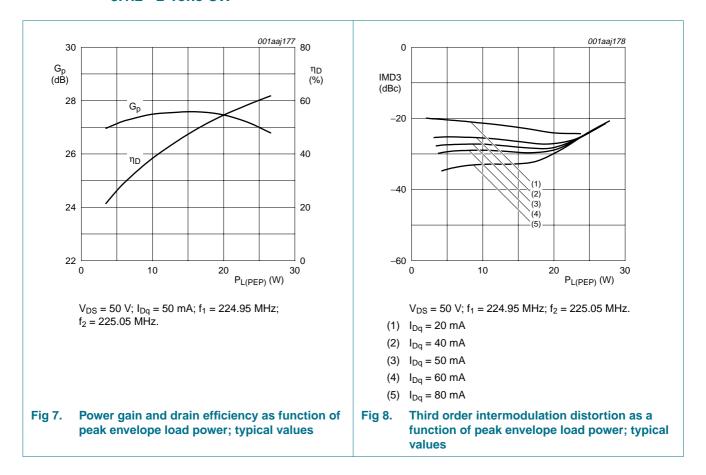
Fig 4. Power gain and drain efficiency as function of load power; typical values

Fig 5. power gain as a function of load power; typical values

### **HF / VHF power LDMOS transistor**



#### 8.1.2 2-Tone CW



#### **HF / VHF power LDMOS transistor**

## 8.2 Test circuit

Table 9. List of components

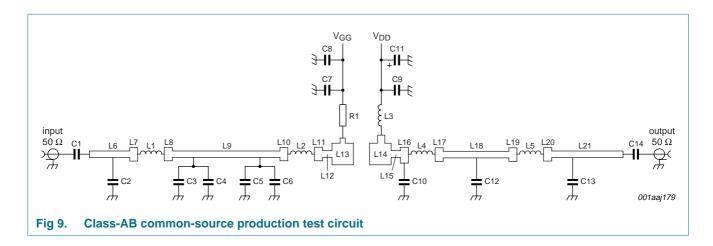
All capacitors should be soldered vertically. For test circuit, see Figure 9 and Figure 10.

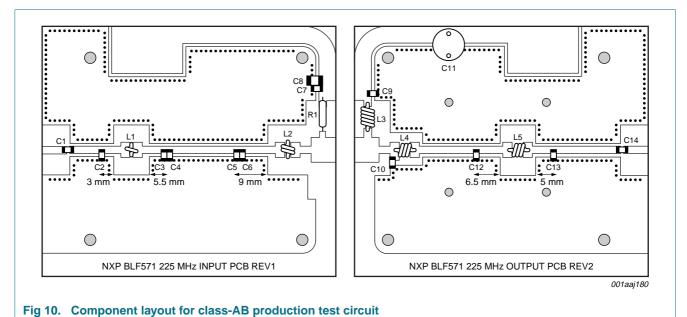
C10         multilayer ceramic chip capacitor         8.2 pF         U           C11         electrolytic capacitor         470 F           C12         multilayer ceramic chip capacitor         33 pF         U           C13         multilayer ceramic chip capacitor         15 pF         U           L1         1 turn enamelled copper wire wire length = 1 mm; length = 1 mm; length = 1 mm; length = 3 mm         C           L2         2 turns enamelled copper wire length = 3 mm         D = 3 mm; d = 1 mm; length = 5 mm           L3         5 turns enamelled copper wire length = 5 mm         D = 3 mm; d = 1 mm; length = 4 mm           L4         3.3 turns enamelled copper wire length = 3 mm         D = 3 mm; d = 1 mm; length = 3 mm           L5         3 turns enamelled copper wire length = 3 mm         D = 3 mm; d = 1 mm; length = 3 mm           L6         stripline         -         2 (L × W) 16.5 mm × 2.4 mm           L7, L8, L10, L10, L11, L17, L19, L20         stripline         -         2 (L × W) 3.0 mm × 2.4 mm           L11, L17, L19, L20         stripline         -         2 (L × W) 3.0 mm × 2.4 mm           L12, L15         stripline         -         2 (L × W) 3.0 mm × 5.9 mm           L13, L14         stripline         -         2 (L × W) 3.0 mm × 2.4 mm           L16         stripline	Component	Description	Value	Remarks
C6         multilayer ceramic chip capacitor         68 pF         U           C7, C9         multilayer ceramic chip capacitor         1 nF         U           C8         multilayer ceramic chip capacitor         4.7 F         TDK C4532X7R1E475MT020U or equivalent           C10         multilayer ceramic chip capacitor         470 F           C11         electrolytic capacitor         33 pF         U           C12         multilayer ceramic chip capacitor         15 pF         U           C13         multilayer ceramic chip capacitor         15 pF         U           C14         1 turn enamelled copper wire         D = 5.5 mm; d = 1 mm; length = 1 mm         Length = 1 mm; length = 3 mm           L2         2 turns enamelled copper wire         D = 3.5 mm; d = 1 mm; length = 3 mm         Length = 3 mm           L3         5 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 4 mm           L4         3.3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 4 mm           L5         3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 3 mm           L6         stripline         -         L2 (L × W) 3.0 mm × 2.4 mm           L6         stripline         -         L2 (L × W) 3.0 mm × 2.4 mm           L7, L8, L10, L11, L17, L19, L20         -		multilayer ceramic chip capacitor	100 pF	<u>[1]</u>
C7, C9         multilayer ceramic chip capacitor         1 nF         II           C8         multilayer ceramic chip capacitor         4.7 F         TDK C4532X7R1E475MT020U or equivalent           C10         multilayer ceramic chip capacitor         4.7 F         TDK C4532X7R1E475MT020U or equivalent           C11         electrolytic capacitor         470 F         II           C12         multilayer ceramic chip capacitor         15 pF         II           C13         multilayer ceramic chip capacitor         15 pF         II           L1         1 turn enamelled copper wire         D = 5.5 mm; d = 1 mm; length = 1 mm           L2         2 turns enamelled copper wire         D = 3.5 mm; d = 1 mm; length = 3 mm           L3         5 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 5 mm           L4         3.3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 4 mm           L5         3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 3 mm           L6         stripline         -         22 (L × W) 16.5 mm × 2.4 mm           L7, L8, L10, L11, L17, L19, L20         stripline         -         22 (L × W) 3.0 mm × 5.0 mm           L9         stripline         -         22 (L × W) 3.0 mm × 2.4 mm           L12, L15         stripline <td< td=""><td>C2</td><td>multilayer ceramic chip capacitor</td><td>39 pF</td><td>[1]</td></td<>	C2	multilayer ceramic chip capacitor	39 pF	[1]
C8         multilayer ceramic chip capacitor         4.7 F         TDK C4532X7R1E475MT020U or equivalent           C10         multilayer ceramic chip capacitor         8.2 pF         [1]           C11         electrolytic capacitor         470 F           C12         multilayer ceramic chip capacitor         15 pF         [1]           C13         multilayer ceramic chip capacitor         15 pF         [1]           L1         1 turn enamelled copper wire ultimate and multilayer ceramic chip capacitor         15 pF         [1]           L1         1 turn enamelled copper wire ultimate and multilayer ceramic chip capacitor         15 pF         [1]           L1         1 turn enamelled copper wire ultimate and multilayer ceramic chip capacitor         15 pF         [1]           L2         2 turns enamelled copper wire ultimate and multilayer ceramic chip capacitor         15 pF         [1]           L3         5 turns enamelled copper wire ultimate and multilayer and multilay	C6	multilayer ceramic chip capacitor	68 pF	[1]
C10         multilayer ceramic chip capacitor         8.2 pF         II           C11         electrolytic capacitor         470 F           C12         multilayer ceramic chip capacitor         33 pF         II           C13         multilayer ceramic chip capacitor         15 pF         II           L1         1 turn enamelled copper wire wire length = 1 mm; length = 1 mm; length = 1 mm; length = 3 mm         - 5.5 mm; d = 1 mm; length = 3 mm           L2         2 turns enamelled copper wire length = 3 mm; d = 1 mm; length = 5 mm         D = 6 mm; d = 1 mm; length = 5 mm           L4         3.3 turns enamelled copper wire d = 1 mm; length = 4 mm         D = 3 mm; d = 1 mm; length = 3 mm           L5         3 turns enamelled copper wire length = 3 mm         - 2 (L × W) 16.5 mm × 2.4 mm           L7, L8, L10, L10, L11, L17, L19, L20         stripline         - 2 (L × W) 3.0 mm × 5.0 mm           L11, L17, L19, L20         stripline         - 2 (L × W) 3.0 mm × 2.4 mm           L12, L15         stripline         - 2 (L × W) 3.0 mm × 8.0 mm           L13         stripline         - 2 (L × W) 3.0 mm × 5.9 mm           L16         stripline         - 2 (L × W) 3.0 mm × 2.4 mm           L16         stripline         - 2 (L × W) 3.0 mm × 2.4 mm           L16         stripline         - 2 (L × W) 3.0 mm × 2.4 mm	C7, C9	multilayer ceramic chip capacitor	1 nF	[1]
C11         electrolytic capacitor         470 F           C12         multilayer ceramic chip capacitor         33 pF         11           C13         multilayer ceramic chip capacitor         15 pF         11           L1         1 turn enamelled copper wire         D = 5.5 mm; d = 1 mm; length = 1 mm           L2         2 turns enamelled copper wire         D = 3.5 mm; d = 1 mm; length = 3 mm           L3         5 turns enamelled copper wire         D = 6 mm; d = 1 mm; length = 5 mm           L4         3.3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 4 mm           L5         3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 3 mm           L6         stripline         -         12 (L × W) 16.5 mm × 2.4 mm           L7, L8, L10, L10, L11, L17, L19, L20         tripline         -         12 (L × W) 3.0 mm × 5.0 mm           L11, L17, L19, L20         tripline         -         12 (L × W) 3.5 mm × 2.4 mm           L12, L15         stripline         -         12 (L × W) 3.0 mm × 8.0 mm           L13, L14         stripline         -         12 (L × W) 3.0 mm × 5.9 mm           L18         stripline         -         12 (L × W) 27.0 mm × 2.4 mm	C8	multilayer ceramic chip capacitor	4.7 F	TDK C4532X7R1E475MT020U or equivalent
C12         multilayer ceramic chip capacitor         33 pF         II           C13         multilayer ceramic chip capacitor         15 pF         II           L1         1 turn enamelled copper wire         D = 5.5 mm; d = 1 mm; length = 1 mm; length = 1 mm; length = 3 mm         L2           L2         2 turns enamelled copper wire d = 1 mm; length = 3 mm         D = 6 mm; d = 1 mm; length = 5 mm           L4         3.3 turns enamelled copper wire length = 5 mm         D = 3 mm; d = 1 mm; length = 4 mm           L5         3 turns enamelled copper wire length = 3 mm         D = 3 mm; d = 1 mm; length = 3 mm           L6         stripline         -         I2 (L × W) 16.5 mm × 2.4 mm           L7, L8, L10, L10, L11, L11, L11, L12, L12, L15         stripline         -         I2 (L × W) 3.0 mm × 5.0 mm           L9         stripline         -         I2 (L × W) 3.5 mm × 2.4 mm           L13, L14         stripline         -         I2 (L × W) 3.0 mm × 5.0 mm           L16         stripline         -         I2 (L × W) 3.0 mm × 2.4 mm           L16         stripline         -         I2 (L × W) 3.0 mm × 5.9 mm           L18         stripline         -         I2 (L × W) 27.0 mm × 2.4 mm           L18         stripline         -         I2 (L × W) 27.0 mm × 2.4 mm	C10	multilayer ceramic chip capacitor	8.2 pF	[1]
C13         multilayer ceramic chip capacitor         15 pF         [1]           L1         1 turn enamelled copper wire         D = 5.5 mm; d = 1 mm; length = 1 mm           L2         2 turns enamelled copper wire         D = 3.5 mm; d = 1 mm; length = 3 mm           L3         5 turns enamelled copper wire         D = 6 mm; d = 1 mm; length = 5 mm           L4         3.3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 4 mm           L5         3 turns enamelled copper wire         D = 3 mm; d = 1 mm; length = 3 mm           L6         stripline         -         [2] (L × W) 16.5 mm × 2.4 mm           L7, L8, L10, L11, L17, L19, L20         stripline         -         [2] (L × W) 3.0 mm × 5.0 mm           L9         stripline         -         [2] (L × W) 43.0 mm × 2.4 mm           L12, L15         stripline         -         [2] (L × W) 3.5 mm × 2.4 mm           L13, L14         stripline         -         [2] (L × W) 3.0 mm × 5.9 mm           L16         stripline         -         [2] (L × W) 27.0 mm × 2.4 mm           L18         stripline         -         [2] (L × W) 27.0 mm × 2.4 mm           L21         stripline         -         [2] (L × W) 28.5 mm × 2.4 mm	C11	electrolytic capacitor	470 F	
L1       1 turn enamelled copper wire length = 1 mm; length = 1 mm; length = 1 mm; length = 3 mm       D = 5.5 mm; d = 1 mm; length = 3 mm         L2       2 turns enamelled copper wire length = 3 mm       D = 6 mm; d = 1 mm; length = 5 mm         L3       5 turns enamelled copper wire length = 5 mm       D = 3 mm; d = 1 mm; length = 4 mm         L4       3.3 turns enamelled copper wire length = 4 mm       D = 3 mm; d = 1 mm; length = 4 mm         L5       3 turns enamelled copper wire length = 3 mm       L (L × W) 16.5 mm × 2.4 mm         L7, L8, L10, L11, L17, L19, L20       Stripline       2 (L × W) 3.0 mm × 5.0 mm         L9       stripline       - 2 (L × W) 43.0 mm × 2.4 mm         L12, L15       stripline       - 2 (L × W) 3.5 mm × 2.4 mm         L13, L14       stripline       - 2 (L × W) 3.0 mm × 5.9 mm         L16       stripline       - 2 (L × W) 3.0 mm × 5.9 mm         L18       stripline       - 2 (L × W) 27.0 mm × 2.4 mm         L21       stripline       - 2 (L × W) 27.0 mm × 2.4 mm	C12	multilayer ceramic chip capacitor	33 pF	[1]
d = 1 mm;   length = 1 mm     L2	C13	multilayer ceramic chip capacitor	15 pF	[1]
d = 1 mm; length = 3 mm         L3       5 turns enamelled copper wire length = 5 mm       D = 6 mm; d = 1 mm; length = 5 mm         L4       3.3 turns enamelled copper wire length = 5 mm       D = 3 mm; d = 1 mm; length = 4 mm         L5       3 turns enamelled copper wire length = 3 mm; d = 1 mm; length = 3 mm       Length = 3 mm         L6       stripline       -       1/2 (L × W) 16.5 mm × 2.4 mm         L7, L8, L10, L11, L17, L19, L20       stripline       -       1/2 (L × W) 3.0 mm × 5.0 mm         L9       stripline       -       1/2 (L × W) 3.5 mm × 2.4 mm         L12, L15       stripline       -       1/2 (L × W) 3.5 mm × 2.4 mm         L13, L14       stripline       -       1/2 (L × W) 3.0 mm × 5.9 mm         L16       stripline       -       1/2 (L × W) 3.0 mm × 5.9 mm         L18       stripline       -       1/2 (L × W) 27.0 mm × 2.4 mm         L21       stripline       -       1/2 (L × W) 27.0 mm × 2.4 mm	L1	1 turn enamelled copper wire	d = 1  mm;	
L4       3.3 turns enamelled copper wire length = 5 mm       D = 3 mm; d = 1 mm; length = 4 mm         L5       3 turns enamelled copper wire length = 4 mm       D = 3 mm; d = 1 mm; length = 3 mm         L6       stripline       -       [2] (L × W) 16.5 mm × 2.4 mm         L7, L8, L10, L11, L17, L19, L20       stripline       -       [2] (L × W) 3.0 mm × 5.0 mm         L9       stripline       -       [2] (L × W) 43.0 mm × 2.4 mm         L12, L15       stripline       -       [2] (L × W) 3.5 mm × 2.4 mm         L13, L14       stripline       -       [2] (L × W) 3.0 mm × 8.0 mm         L16       stripline       -       [2] (L × W) 3.0 mm × 5.9 mm         L18       stripline       -       [2] (L × W) 27.0 mm × 2.4 mm         L21       stripline       -       [2] (L × W) 28.5 mm × 2.4 mm	L2	2 turns enamelled copper wire	d = 1 mm;	
L5       3 turns enamelled copper wire length = 4 mm       D = 3 mm; d = 1 mm; length = 3 mm         L6       stripline       - $\frac{12}{2}$ (L × W) 16.5 mm × 2.4 mm         L7, L8, L10, L17, L19, L20       stripline       - $\frac{12}{2}$ (L × W) 3.0 mm × 5.0 mm         L9       stripline       - $\frac{12}{2}$ (L × W) 43.0 mm × 2.4 mm         L12, L15       stripline       - $\frac{12}{2}$ (L × W) 8.0 mm × 8.0 mm         L13, L14       stripline       - $\frac{12}{2}$ (L × W) 3.0 mm × 5.9 mm         L16       stripline       - $\frac{12}{2}$ (L × W) 27.0 mm × 2.4 mm         L18       stripline       - $\frac{12}{2}$ (L × W) 27.0 mm × 2.4 mm         L21       stripline       - $\frac{12}{2}$ (L × W) 27.0 mm × 2.4 mm	L3	5 turns enamelled copper wire	d = 1 mm;	
d = 1 mm; length = 3 mm         L6       stripline       -       2 (L × W) 16.5 mm × 2.4 mm         L7, L8, L10, L11, L17, L19, L20       -       2 (L × W) 3.0 mm × 5.0 mm         L9       stripline       -       2 (L × W) 43.0 mm × 2.4 mm         L12, L15       stripline       -       2 (L × W) 3.5 mm × 2.4 mm         L13, L14       stripline       -       2 (L × W) 8.0 mm × 8.0 mm         L16       stripline       -       2 (L × W) 3.0 mm × 5.9 mm         L18       stripline       -       2 (L × W) 27.0 mm × 2.4 mm         L21       stripline       -       2 (L × W) 28.5 mm × 2.4 mm	L4	3.3 turns enamelled copper wire	d = 1 mm;	
L7, L8, L10, L11, L17, L19, L20       stripline       -       [2] (L × W) 3.0 mm × 5.0 mm         L9       stripline       -       [2] (L × W) 43.0 mm × 2.4 mm         L12, L15       stripline       -       [2] (L × W) 3.5 mm × 2.4 mm         L13, L14       stripline       -       [2] (L × W) 8.0 mm × 8.0 mm         L16       stripline       -       [2] (L × W) 3.0 mm × 5.9 mm         L18       stripline       -       [2] (L × W) 27.0 mm × 2.4 mm         L21       stripline       -       [2] (L × W) 28.5 mm × 2.4 mm	L5	3 turns enamelled copper wire	d = 1 mm;	
L11, L17, L19, L20         L9       stripline       -       [2] (L × W) 43.0 mm × 2.4 mm         L12, L15       stripline       -       [2] (L × W) 3.5 mm × 2.4 mm         L13, L14       stripline       -       [2] (L × W) 8.0 mm × 8.0 mm         L16       stripline       -       [2] (L × W) 3.0 mm × 5.9 mm         L18       stripline       -       [2] (L × W) 27.0 mm × 2.4 mm         L21       stripline       -       [2] (L × W) 28.5 mm × 2.4 mm	L6	stripline	-	[2] (L × W) 16.5 mm × 2.4 mm
L12, L15       stripline       -       [2] (L × W) 3.5 mm × 2.4 mm         L13, L14       stripline       -       [2] (L × W) 8.0 mm × 8.0 mm         L16       stripline       -       [2] (L × W) 3.0 mm × 5.9 mm         L18       stripline       -       [2] (L × W) 27.0 mm × 2.4 mm         L21       stripline       -       [2] (L × W) 28.5 mm × 2.4 mm	L11, L17, L19,	stripline	-	[2] (L × W) 3.0 mm × 5.0 mm
L13, L14       stripline       -       [2] (L × W) 8.0 mm × 8.0 mm         L16       stripline       -       [2] (L × W) 3.0 mm × 5.9 mm         L18       stripline       -       [2] (L × W) 27.0 mm × 2.4 mm         L21       stripline       -       [2] (L × W) 28.5 mm × 2.4 mm	L9	stripline	-	[2] (L × W) 43.0 mm × 2.4 mm
L16       stripline       - $           \begin{bmatrix}             2           \end{bmatrix}         $ (L × W) 3.0 mm × 5.9 mm         L18       stripline       - $           \begin{bmatrix}             2           \end{bmatrix}         $ (L × W) 27.0 mm × 2.4 mm         L21       stripline       - $           \begin{bmatrix}             2           \end{bmatrix}         $ (L × W) 28.5 mm × 2.4 mm	L12, L15	stripline	-	[2] (L × W) 3.5 mm × 2.4 mm
L18       stripline       - $(L \times W)$ 27.0 mm × 2.4 mm         L21       stripline       - $(L \times W)$ 28.5 mm × 2.4 mm	L13, L14	stripline	-	[2] (L × W) 8.0 mm × 8.0 mm
L21 stripline - [2] (L × W) 28.5 mm × 2.4 mm	L16	stripline	-	[2] (L × W) 3.0 mm × 5.9 mm
. ,	L18	stripline	-	[2] (L × W) 27.0 mm × 2.4 mm
R1 metal film resistor 1000 Ω: 0.6 W	L21	stripline	-	[2] (L × W) 28.5 mm × 2.4 mm
1000 111	R1	metal film resistor	1000 Ω; 0.6 W	

<sup>[1]</sup> American Technical Ceramics type 100B or capacitor of same quality.

<sup>[2]</sup> Printed-Circuit Board (PCB): Rogers 5880;  $\epsilon_r$  = 2.2 F/m; height = 0.79 mm; Cu (top/bottom metallization); thickness copper plating = 35  $\mu$ m.

#### **HF / VHF power LDMOS transistor**





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#### **HF / VHF power LDMOS transistor**

# **Package outline**

#### Flanged LDMOST ceramic package; 2 mounting holes; 2 leads

**SOT467C** 

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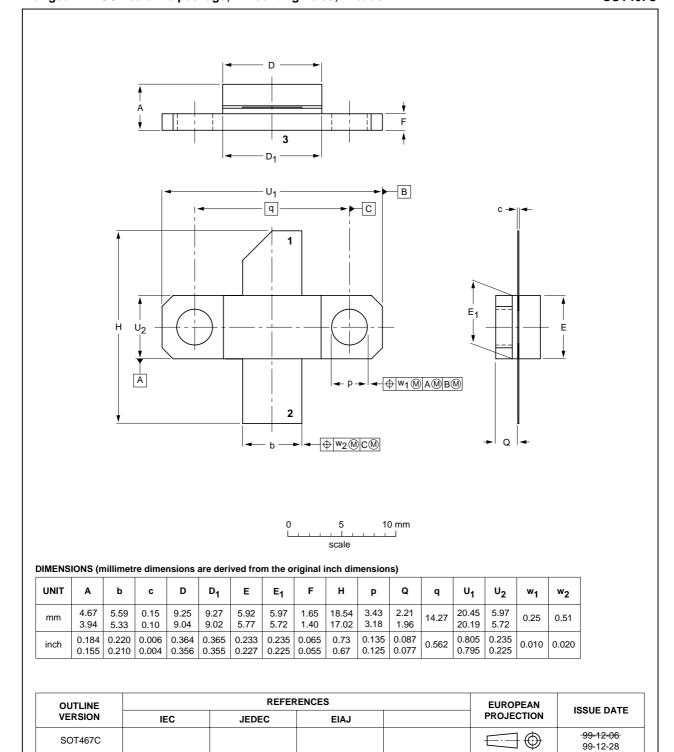


Fig 11. Package outline SOT467C

Preliminary data sheet

### **HF / VHF power LDMOS transistor**

# 10. Abbreviations

Table 10. Abbreviations

Acronym	Description
CW	Continuous Wave
EDGE	Enhanced Data rates for GSM Evolution
GSM	Global System for Mobile communications
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
RF	Radio Frequency
TTF	Time To Failure
VHF	Very High Frequency
VSWR	Voltage Standing-Wave Ratio

# 11. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF571_1	20081211	Preliminary data sheet	-	-

#### **HF / VHF power LDMOS transistor**

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### **HF / VHF power LDMOS transistor**

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